### BDX33B BDX33C BDX34B BDX34C

#### THERMAL DATA

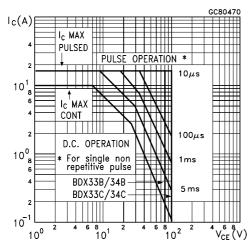
R <sub>thj-case</sub> Thermal Resistance Junction-case	1.78	°C/W	Ī
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## **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector Cut-off Current (I <sub>E</sub> = 0)	for <b>BDX33B/34B</b> $V_{CB} = 80 \text{ V}$ for <b>BDX33C/34C</b> $V_{CB} = 100 \text{ V}$ $T_{case} = 100 ^{\circ}\text{C}$			0.2 0.2	mA mA
		for BDX33B/34B $V_{CB} = 80 \text{ V}$ for BDX33C/34C $V_{CB} = 100 \text{ V}$			5 5	mA mA
I <sub>CEO</sub>	Collector Cut-off Current (I <sub>B</sub> = 0)	for <b>BDX33B/34B</b> $V_{CE} = 40 \text{ V}$ for <b>BDX33C/34C</b> $V_{CE} = 50 \text{V}$ $V_{CE} = 100 \text{ °C}$ for <b>BDX33B/34B</b> $V_{CE} = 40 \text{ V}$ for <b>BDX33C/34C</b> $V_{CE} = 50 \text{ V}$			0.5 0.5 10 10	mA mA mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V			5	mA
V <sub>CEO(sus)</sub> *	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> =100 mA for <b>BDX33B/34B</b> for <b>BDX33C/34C</b>	80 100			V V
V <sub>CER(sus)</sub> *	Collector-emitter Sustaining Voltage ( $R_{BE} = 100 \Omega$ )	I <sub>C</sub> = 100 mA for <b>BDX33B/34B</b> for <b>BDX33C/34C</b>	80 100			V V
V <sub>CEV(sus)</sub> *	Collector-emitter Sustaining Voltage (V <sub>BE</sub> =-1.5 V)	I <sub>C</sub> = 100 mA for <b>BDX33B/34B</b> for <b>BDX33C/34C</b>	80 100			V V
V <sub>CE(sat)</sub> *	Collector-emitter Saturation Voltage	$I_C = 3 \text{ A}$ $I_B = 6 \text{ mA}$			2.5	V
V <sub>BE</sub> *	Base-emitter Voltage	I <sub>C</sub> = 3 A V <sub>CE</sub> = 3 V			2.5	V
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 3 A V <sub>CE</sub> = 3 V	750			V
V <sub>F</sub> *	Parallel-Diode Forward Voltage	I <sub>F</sub> = 8 A		_	4	V
h <sub>fe</sub>	Small Signal Current Gain	$I_C = 1 A  V_{CE} = 5 V  f = 1MHz$	100			

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

## Safe Operating Area

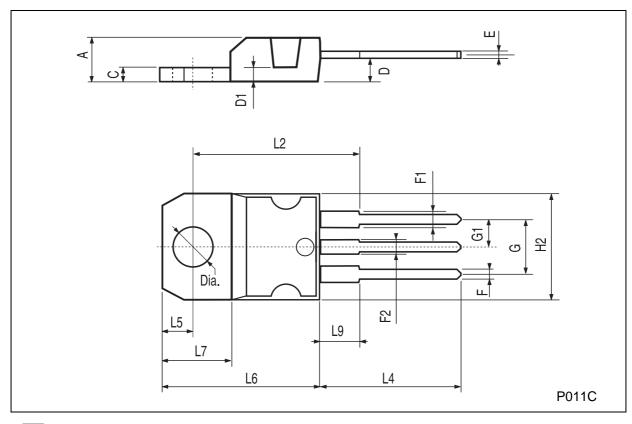


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For PNP types voltage and current values are negative.

# **TO-220 MECHANICAL DATA**

DIM.		mm				
Dilvi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	4.40		4.60	0.173		0.181
С	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
D1		1.27			0.050	
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137		0.154
DIA.	3.75		3.85	0.147		0.151



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